SN54HCT245, SN74HCT245 **OCTAL BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS

SCLS020C - MARCH 1984 - REVISED MAY 1997

- Inputs Are TTL-Voltage Compatible
- **High-Current 3-State Outputs Drive Bus** Lines Directly or up to 15 LSTTL Loads
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

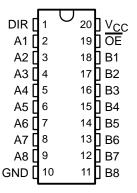
description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

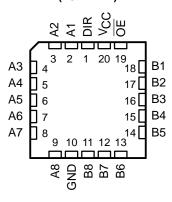
The devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

The SN54HCT245 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HCT245 is characterized for operation from -40°C to 85°C.

SN54HCT245...J OR W PACKAGE SN74HCT245 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54HCT245 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE

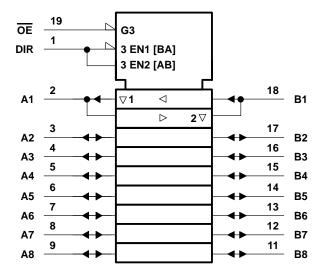
INP	UTS	OPERATION				
Œ	DIR	OPERATION				
L	L	B data to A bus				
L	Н	A data to B bus				
Н	Χ	Isolation				



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

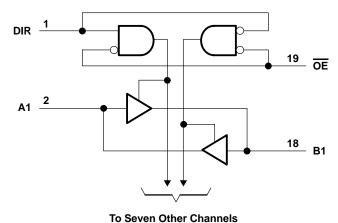


logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



TEXAS INSTRUMENTS

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absolute maximum ratings over operating free-air temperature range[†]

Supply voltage range, V _{CC}		0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (se	ee Note 1)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	c) (see Note 1)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})		±35 mA
Continuous current through V _{CC} or GND		±70 mA
Package thermal impedance, θ _{JA} (see Note 2):	DB package	115°C/W
	DW package	97°C/W
	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T _{stg}		. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN	SN54HCT245			SN74HCT245		
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2			2			V
V _{IL}	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V	0		0.8	0		0.8	V
٧ _I	Input voltage		0		VCC	0		VCC	V
٧o	Output voltage		0		VCC	0		VCC	V
t _t	Input transition (rise and fall) time		0		500	0		500	ns
T _A	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAR	AMETED	TEST CONDITIONS		Vaa	T _A = 25°C			SN54HCT245		SN74HCT245		UNIT
PARAMETER		1231 001	ADITIONS	vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
Va		\\ \\ or \\	$I_{OH} = -20 \mu A$	4.5 V	4.4	4.499		4.4		4.4		V
VOH		VI = VIH or VIL	$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		V
Vai		\\ \\ or \\	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL		VI = VIH or VIL	$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
lį	DIR or OE	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
loz	A or B	VO = VCC or 0		5.5 V		±0.01	±0.5		±10		±5	μΑ
Icc		$V_I = V_{CC}$ or 0,	IO = 0	5.5 V			8		160		80	μΑ
∆lcc‡		One input at 0.5 V Other inputs at 0 of		5.5 V		1.4	2.4		3		2.9	mA
C _i §	DIR or OE			4.5 V to 5.5 V		3	10		10		10	pF

[‡]This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

[§] Parameter C_i does not apply to transceiver I/O ports.

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switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	ТО		T,	չ = 25°C	;	SN54H	CT245	SN74H	CT245	UNIT	
FARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT	
+ .	A or B	B or A	4.5 V		16	22		33		28	nc	
ιра	t _{pd} A or B	B or A	BUIA	5.5 V		14	20		30		25	ns
+	OE	A or B	4.5 V		25	46		69		58		
^t en	OE	AUID	5.5 V		22	41		62		52	ns	
.		OE A or B	4.5 V		26	40		60		50	20	
^t dis	OE OE		5.5 V		23	36		54		45	ns	
t _t		A or D	4.5 V		9	12		18		15	ns	
		A or B	AUID	5.5 V		8	11		16		14	115

switching characteristics over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Figure 1)

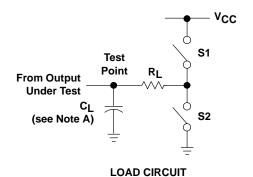
PARAMETER	FROM	то	Vaa	T,	չ = 25°C	;	SN54H	CT245	SN74H	CT245	UNIT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	A or B	B or A	4.5 V		20	30		45		38	20
^t pd	AUID		5.5 V		18	27		41		34	ns
	<u>OE</u>	A or B	4.5 V		36	59		89		74	20
^t en	OE		AUID	5.5 V		30	53		80		67
t _t		A or B	4.5 V		17	42		63		53	20
			5.5 V		14	38		57		48	ns

operating characteristics, $T_A = 25^{\circ}C$

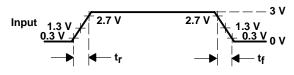
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per transceiver	No load	40	pF

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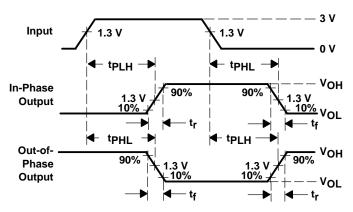
PARAMETER MEASUREMENT INFORMATION

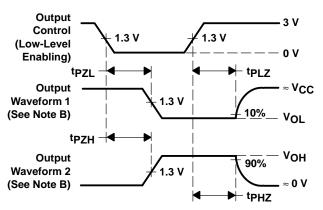


PARAM	/IETER	RL	CL	S1	S2	
	tPZH	1 k Ω	50 pF or	Open	Closed	
ten	tPZL	1 K22	150 pF	Closed	Open	
.	^t PHZ	1 k Ω	50 pF	Open	Closed	
^t dis	tPLZ	1 K22	30 pi	Closed	Open	
t _{pd} or	t _{pd} or t _t		50 pF or 150 pF	Open	Open	



VOLTAGE WAVEFORM INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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